[5+5]

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Code No: 121AD  JAWAHARLAL NEHRU TECHNOLOGICAL UNIVERSITY HYDERAB  B.Tech I Year Examinations, August/September - 2017  ENGINEERING PHYSICS	
(Common to CE, EEE, ME, ECE, CSE, EIE, IT, MCT, ETM, MMT, AE, AME, M	IE, PTE,
CEE, MSNT)	Tarks: 75
Note: This question paper contains two parts A and B.  Part A is compulsory which carries 25 marks. Answer all questions in Part B consists of 5 Units. Answer any one full question from each unquestion carries 10 marks and may have a, b, c as sub questions.  PART- A	Part A. nit. Each
	[2]
<ul> <li>What is Bravais lattice? What are the different space lattices in cubic system? Explain with suitable diagram, the Powder method of determination of crystal statistics.</li> <li>Explain the Physical significance of wave function. Give three differences between Bose-Einstein and Fermi Dirac statistics.</li> <li>Define displacement vector and electric susceptibility.</li> <li>Explain Hysteresis of ferro-magnetic material.</li> <li>Give the condition for bright and dark band in interference of reflected light in the Define spontaneous, stimulated emission of radiation and population inversion.</li> <li>Draw the I-V characteristics of PN junction diode.</li> <li>What is nanotechnology? Give one method of each- Top down and Bottom up for fabrication of nanomaterials.</li> </ul>	[3] [2] [3] [3] thin films. [2] [3]
PART-B	70 N/L - L-
	50 Marks
<ul> <li>2.a) Define Unit Cell, lattice parameter and coordination number.</li> <li>b) Obtain an expression for the packing factor of FCC structure.</li> </ul>	[5+5]
<ul><li>3.a) Derive Bragg's law of X-ray diffraction.</li><li>b) Describe with neat diagram Laue's method of determination of crystal structure.</li></ul>	e. [5+5]
<ul><li>4.a) What are matter waves. Explain their properties.</li><li>b) Explain the de-Broglie hypothesis. Explain G.P.Thomson's experiment in suppopulation.</li></ul>	ort of this [5+5]

Derive and expression for density of states of electrons.

Define effective mass of an electron. Explain its significance.

hypothesis.

5.a)

b)

	Explain Electric susceptibility, Electric polarization. Give a relation between the tr	
6.a) b)	Describe Lorentz method to calculate the internal field of a cubic structure.	[5+5]
U)	OR	
7.a) b)	Explain the differences between hard and soft magnetic materials.  Define the terms magnetic moment (B), magnetization (M) and magnetic Obtain an expression relating to these quantities.	([s :1 .
8.a) Explain the concept of coherence. What are the necessary conditions for constructive and		
8.a) b)	destructive interference?  What is double refraction? Discuss the construction of Nicol prism.  OR	[5+5]
9.a) b)	Describe the construction of GaAs semiconductor laser.  Derive an expression for acceptance angle for an optical fiber. How is it numerical aperture?	related to [5+5]
10.a) b)	Derive an expression for the carrier concentration of p-type semiconductors. An auditorium has a volume of 5000m <sup>3</sup> . What should be the total absorption in the reverberation time of 1.25 seconds is to be maintained?	n the hall if
11.a) b)	What are nanomaterials? Why do they exhibit different properties?  Describe the bottom up methods by which nanomaterials are fabricated.	[5+5]

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